

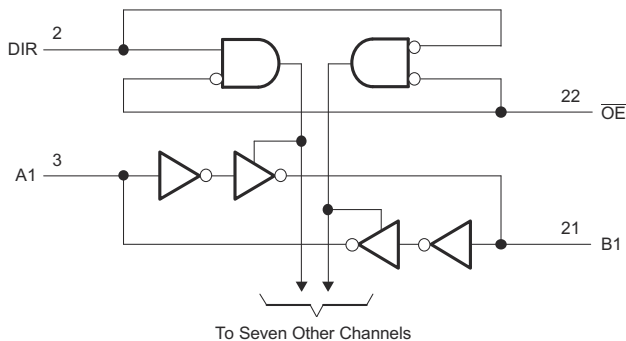
## SN74LVCH8T245 8 ビットデュアル電源バス・トランシーバ、 構成可能レベルシフト、電圧変換、3ステート出力

### 1 特長

- 制御入力 (DIR および  $\overline{OE}$ ) の  $V_{IH}$  および  $V_{IL}$  レベルは  $V_{CCA}$  基準
- データ入力のバス・ホールド機能により、外付けプルアップ/プルダウン抵抗が不要
- $V_{CC}$  絶縁機能
- 完全に構成可能なデュアル・レール設計
- $I_{off}$  により部分的パワーダウン・モードでの動作をサポート
- JESD 78、Class II 準拠で 100mA 超のラッチアップ性能
- JESD 22 を上回る ESD 保護

### 2 アプリケーション

- パーソナル・エレクトロニクス
- 産業用
- エンタープライズ
- 電気通信



論理図 (正論理)

### 3 概要

SN74LVCH8T245 は、設定可能な 2 本の独立した電源レールを採用した 8 ビット非反転バス・トランシーバです。A ポートは  $V_{CCA}$  に追従するように設計されており、1.65V ~ 5.5V の電源電圧に対応します。B ポートは  $V_{CCB}$  に追従するように設計されており、1.65V ~ 5.5V の電源電圧に対応します。このため、1.8V、2.5V、3.3V、5.5V の任意の電圧ノード間での自在な低電圧双方向変換が可能です。

SN74LVCH8T245 は、2 つのデータ・バス間の非同期通信用に設計されています。方向制御 (DIR) 入力および出力イネーブル ( $\overline{OE}$ ) 入力のロジック・レベルに応じて、B ポート出力もしくは A ポート出力のいずれかがアクティブになるか、または、両方の出力ポートが高インピーダンス状態になります。本デバイスは、B ポート出力がアクティブになった場合、A バスから B バスへデータを転送し、A ポート出力がアクティブになった場合、B バスから A バスへデータを転送します。A ポートおよび B ポートの入力回路は、どちらも常にアクティブです。

アクティブ・バス・ホールド回路により、使用されていない、または駆動されていない入力を有効なロジック状態に保持します。プルアップまたはプルダウン抵抗とバス・ホールド回路との併用は推奨しません。このデバイスは、 $I_{off}$  を使用する部分的パワーダウン・アプリケーション用の動作が完全に規定されています。 $I_{off}$  回路が出力をディセーブルにするため、デバイスに電流が逆流して損傷に至ることを回避できます。 $V_{CC}$  絶縁機能は、 $V_{CCA}$  または  $V_{CCB}$  のいずれかが GND レベルになった場合、出力を確実に高インピーダンス状態にします。電源オンまたは電源オフ時に高インピーダンス状態を確保するため、 $\overline{OE}$  はプルアップ抵抗経由で  $V_{CCA}$  に接続する必要があります。この抵抗の最小値は、ドライバの電流シンク能力によって決定されます。

SN74LVCH8T245 は、制御ピン (DIR および  $\overline{OE}$ ) が  $V_{CCA}$  を基準とするよう設計されています。

#### パッケージ情報 (1)

部品番号	パッケージ	本体サイズ (公称)
SN74LVCH8T245	DB (SSOP, 24)	8.65mm × 3.90mm
	DGV (TVSOP, 24)	5.00mm × 4.40mm
	PW (TSSOP, 24)	7.80mm × 4.40mm
	RHL (VQFN, 24)	5.50mm × 3.50mm

- (1) 利用可能なパッケージについては、このデータシートの末尾にある注文情報を参照してください。



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## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision B (January 2016) to Revision C (December 2022)	Page
• 文書全体にわたって表、図、相互参照の採番方法を更新.....	1
• Updated thermals for PW package.....	5
• Removed the <i>Supports High-Speed Translation</i> and added the <i>Balanced High-Drive CMOS Push-Pull Outputs</i> section.....	13

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Changes from Revision A (February 2007) to Revision B (January 2016)	Page
• 「ESD 定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加.....	1

## 5 Pin Configuration and Functions

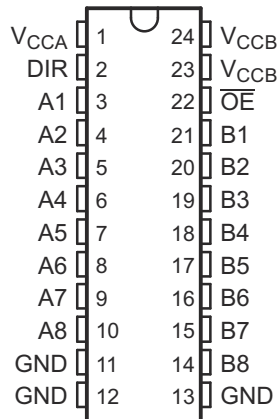


图 5-1. DB, DGV, or PW Packages, 24-Pin SSOP, TVSOP, or TSSOP (Top View)

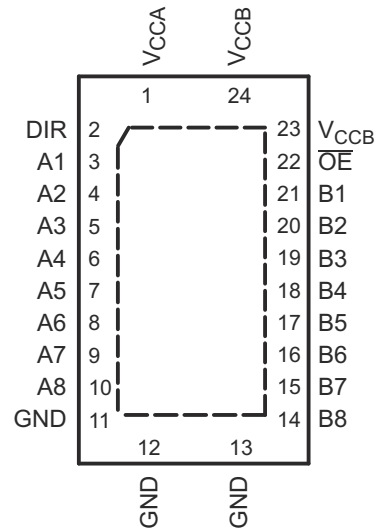


图 5-2. RHL Package, 24-Pin VQFN (Top View)

表 5-1. Pin Functions

NAME	PIN		TYPE <sup>(1)</sup>	DESCRIPTION
	SSOP, TVSOP, TSSOP	VQFN		
A1	3	3	I/O	Input/output A1. Referenced to $V_{CCA}$ .
A2	4	4	I/O	Input/output A2. Referenced to $V_{CCA}$ .
A3	5	5	I/O	Input/output A3. Referenced to $V_{CCA}$ .
A4	6	6	I/O	Input/output A4. Referenced to $V_{CCA}$ .
A5	7	7	I/O	Input/output A5. Referenced to $V_{CCA}$ .
A6	8	8	I/O	Input/output A6. Referenced to $V_{CCA}$ .
A7	9	9	I/O	Input/output A7. Referenced to $V_{CCA}$ .
A8	10	10	I/O	Input/output A8. Referenced to $V_{CCA}$ .
B1	21	21	I/O	Input/output B1. Referenced to $V_{CCB}$ .
B2	20	20	I/O	Input/output B2. Referenced to $V_{CCB}$ .
B3	19	19	I/O	Input/output B3. Referenced to $V_{CCB}$ .
B4	18	18	I/O	Input/output B4. Referenced to $V_{CCB}$ .
B5	17	17	I/O	Input/output B5. Referenced to $V_{CCB}$ .
B6	16	16	I/O	Input/output B6. Referenced to $V_{CCB}$ .
B7	15	15	I/O	Input/output B7. Referenced to $V_{CCB}$ .
B8	14	14	I/O	Input/output B8. Referenced to $V_{CCB}$ .
DIR	2	2	I	Direction-control signal. Referenced to $V_{CCA}$ .
$\overline{OE}$	22	22	I	3-state output-mode enables. Pull $\overline{OE}$ high to place all outputs in 3-state mode. Referenced to $V_{CCA}$ .
$V_{CCA}$	1	1	—	A-port supply voltage. $1.65\text{ V} \leq V_{CCA} \leq 5.5\text{ V}$
$V_{CCB}$	23, 24	23, 24	—	B-port supply voltage. $1.65\text{ V} \leq V_{CCA} \leq 5.5\text{ V}$
GND	11, 12, 13	11, 12, 13	—	Ground

(1) I = input, O = output

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage	$V_{CCA}$ and $V_{CCB}$	-0.5	6.5	V
Input voltage <sup>(2)</sup>	I/O ports (A port)	-0.5	6.5	V
	I/O ports (B port)	-0.5	6.5	
	Control inputs	-0.5	6.5	
Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	A port	-0.5	6.5	V
	B port	-0.5	6.5	
Voltage range applied to any output in the high or low state <sup>(2) (3)</sup>	A port	-0.5	$V_{CCA} + 0.5$	V
	B port	-0.5	$V_{CCB} + 0.5$	
Input clamp current	$V_I < 0$		-50	mA
Output clamp current	$V_O < 0$		-50	mA
Continuous output current, $I_O$			±50	mA
Continuous through current	$V_{CCA}$ , $V_{CCB}$ , and GND		±100	mA
Junction temperature, $T_J$		-40	150	°C
Storage temperature, $T_{stg}$		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under [セクション 6.3](#). Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

### 6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±4000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000
		Machine model (MM)	±200

- (1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2) (3)</sup>

		MIN	MAX	UNIT	
$V_{CCA}$	Supply voltage	1.65	5.5	V	
$V_{CCB}$		1.65	5.5		
$V_{IH}$	High-level input voltage <sup>(1)</sup>	Data inputs <sup>(4)</sup>	$V_{CCI} = 1.65 \text{ V to } 4.5 \text{ V}$	$V_{CCI} \times 0.65$	V
			$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	
			$V_{CCI} = 3 \text{ V to } 3.6 \text{ V}$	2	
			$V_{CCI} = 4.5 \text{ V to } 5.5 \text{ V}$	$V_{CCI} \times 0.7$	
$V_{IL}$	Low-level input voltage <sup>(1)</sup>	Data inputs <sup>(4)</sup>	$V_{CCI} = 1.65 \text{ V to } 4.5 \text{ V}$	$V_{CCI} \times 0.35$	V
			$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	0.7	
			$V_{CCI} = 3 \text{ V to } 3.6 \text{ V}$	0.8	
			$V_{CCI} = 4.5 \text{ V to } 5.5 \text{ V}$	$V_{CCI} \times 0.3$	

### 6.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2) (3)</sup>

			MIN	MAX	UNIT
V <sub>IH</sub>	High-level input voltage	Control inputs (referenced to V <sub>CCA</sub> ) <sup>(5)</sup>	V <sub>CCI</sub> = 1.65 V to 4.5 V	V <sub>CCA</sub> × 0.65	V
			V <sub>CCI</sub> = 2.3 V to 2.7 V	1.7	
			V <sub>CCI</sub> = 3 V to 3.6 V	2	
			V <sub>CCI</sub> = 4.5 V to 5.5 V	V <sub>CCA</sub> × 0.7	
V <sub>IL</sub>	Low-level input voltage	Control inputs (referenced to V <sub>CCA</sub> ) <sup>(5)</sup>	V <sub>CCI</sub> = 1.65 V to 4.5 V	V <sub>CCA</sub> × 0.35	V
			V <sub>CCI</sub> = 2.3 V to 2.7 V	0.7	
			V <sub>CCI</sub> = 3 V to 3.6 V	0.8	
			V <sub>CCI</sub> = 4.5 V to 5.5 V	V <sub>CCA</sub> × 0.3	
V <sub>I</sub>	Input voltage	Control inputs <sup>(3)</sup>	0	5.5	V
V <sub>I/O</sub>	Input/output voltage <sup>(2)</sup>	Active state	0	V <sub>CCO</sub>	V
		3-State	0	5.5	
I <sub>OH</sub>	High-level output current		V <sub>CCO</sub> = 1.65 V to 4.5 V	–4	mA
			V <sub>CCO</sub> = 2.3 V to 2.7 V	–8	
			V <sub>CCO</sub> = 3 V to 3.6 V	–24	
			V <sub>CCO</sub> = 4.5 V to 5.5 V	–32	
I <sub>OL</sub>	Low-level output current		V <sub>CCO</sub> = 1.65 V to 4.5 V	4	mA
			V <sub>CCO</sub> = 2.3 V to 2.7 V	8	
			V <sub>CCO</sub> = 3 V to 3.6 V	24	
			V <sub>CCO</sub> = 4.5 V to 5.5 V	32	
Δt/Δv	Input transition rise or fall rate	Data inputs	V <sub>CCI</sub> = 1.65 V to 4.5 V	20	ns/V
			V <sub>CCI</sub> = 2.3 V to 2.7 V	20	
			V <sub>CCI</sub> = 3 V to 3.6 V	10	
			V <sub>CCI</sub> = 4.5 V to 5.5 V	5	
T <sub>A</sub>	Operating free-air temperature		–40	85	°C

(1) V<sub>CCI</sub> is the V<sub>CC</sub> associated with the data input port.

(2) V<sub>CCO</sub> is the V<sub>CC</sub> associated with the output port.

(3) All unused control inputs of the device must be held at V<sub>CCA</sub> or GND to ensure proper device operation and minimize power consumption. See *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

(4) For V<sub>CCI</sub> values not specified in the data sheet, V<sub>IH</sub> min = V<sub>CCI</sub> × 0.7 V, V<sub>IL</sub> (max) = V<sub>CCI</sub> × 0.3 V.

(5) For V<sub>CCA</sub> values not specified in the data sheet, V<sub>IH</sub> min = V<sub>CCA</sub> × 0.7 V, V<sub>IL</sub> (max) = V<sub>CCA</sub> × 0.3 V.

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	SN74LVCH8T245				UNIT	
	DB (SSOP)	DGV (TVSOP)	PW (TSSOP)	RHL (VQFN)		
	24 PINS	24 PINS	24 PINS	24 PINS		
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	88.5	91.1	100.6	37.4	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	48.7	23.7	44.7	38.1	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	44.1	44.5	55.8	15.2	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	12.8	0.6	6.8	0.7	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	43.6	44.1	55.4	15.2	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	—	—	—	4.3	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Electrical Characteristics

All typical limits apply over  $T_A = 25^\circ\text{C}$ , and all maximum and minimum limits apply over  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$  (unless otherwise noted).<sup>(1) (2)</sup>

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT		
$V_{OH}$	High-level output voltage <sup>(1)</sup>	$I_{OH} = -100\ \mu\text{A}$ , $V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$	$V_{CCO} = 0.1$		V		
		$I_{OH} = -4\ \text{mA}$ , $V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$	1.2				
		$I_{OH} = -8\ \text{mA}$ , $V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 2.3\ \text{V}$	1.9				
		$I_{OH} = -24\ \text{mA}$ , $V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 3\ \text{V}$	2.4				
		$I_{OH} = -32\ \text{mA}$ , $V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 4.5\ \text{V}$	3.8				
$V_{OL}$	Low-level output voltage	$I_{OL} = 100\ \mu\text{A}$ , $V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$		0.1	V		
		$I_{OL} = 4\ \text{mA}$ , $V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$		0.45			
		$I_{OL} = 8\ \text{mA}$ , $V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 2.3\ \text{V}$		0.3			
		$I_{OL} = 24\ \text{mA}$ , $V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 3\ \text{V}$		0.55			
		$I_{OL} = 32\ \text{mA}$ , $V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 4.5\ \text{V}$		0.55			
$I_I$	Control inputs	$V_I = V_{CCA}$ or GND	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$		$\pm 0.5$	$\pm 2$	$\mu\text{A}$	
$I_{BHL}$ <sup>(3)</sup>	Bus-hold low sustaining current	$V_I = 0.58\ \text{V}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$		15	$\mu\text{A}$		
		$V_I = 0.7\ \text{V}$	$V_{CCA} = V_{CCB} = 2.3\ \text{V}$		45			
		$V_I = 0.8\ \text{V}$	$V_{CCA} = V_{CCB} = 3\ \text{V}$		75			
		$V_I = 1.35\ \text{V}$	$V_{CCA} = V_{CCB} = 4.5\ \text{V}$		100			
$I_{BHH}$ <sup>(4)</sup>	Bus-hold high sustaining current	$V_I = 1.07\ \text{V}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$		-15	$\mu\text{A}$		
		$V_I = 1.7\ \text{V}$	$V_{CCA} = V_{CCB} = 2.3\ \text{V}$		-45			
		$V_I = 2\ \text{V}$	$V_{CCA} = V_{CCB} = 3\ \text{V}$		-75			
		$V_I = 3.15\ \text{V}$	$V_{CCA} = V_{CCB} = 4.5\ \text{V}$		-100			
$I_{BHLO}$ <sup>(5)</sup>	Bus-hold low overdrive current	$V_I = 0$ to $V_{CC}$	$V_{CCA} = V_{CCB} = 1.95\ \text{V}$		200	$\mu\text{A}$		
			$V_{CCA} = V_{CCB} = 2.7\ \text{V}$		300			
			$V_{CCA} = V_{CCB} = 3.6\ \text{V}$		500			
			$V_{CCA} = V_{CCB} = 5.5\ \text{V}$		900			
$I_{BHHO}$ <sup>(6)</sup>	Bus-hold high overdrive current	$V_I = 0$ to $V_{CC}$	$V_{CCA} = V_{CCB} = 1.95\ \text{V}$		-200	$\mu\text{A}$		
			$V_{CCA} = V_{CCB} = 2.7\ \text{V}$		-300			
			$V_{CCA} = V_{CCB} = 3.6\ \text{V}$		-500			
			$V_{CCA} = V_{CCB} = 5.5\ \text{V}$		-900			
$I_{off}$	Input and output power-off leakage current	$V_I$ or $V_O = 0$ to $5.5\ \text{V}$	$V_{CCA} = 0\ \text{V}$ , $V_{CCB} = 0$ to $5.5\ \text{V}$	A Port	$\pm 0.5$	$\pm 2$	$\mu\text{A}$	
			$V_{CCA} = 0$ to $5.5\ \text{V}$ , $V_{CCB} = 0\ \text{V}$	B Port	$\pm 0.5$	$\pm 2$		
$I_{OZ}$	Off-state output current	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND	$OE = V_{IH}$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$	A Port, B Port		$\pm 2$	$\mu\text{A}$
			$OE = X$	$V_{CCA} = 0\ \text{V}$ , $V_{CCB} = 5.5\ \text{V}$	B Port		$\pm 2$	
				$V_{CCA} = 5.5\ \text{V}$ , $V_{CCB} = 0\ \text{V}$	A Port		$\pm 2$	
$I_{CCA}$	Supply current A port	$V_I = V_{CCI}$ or GND, $I_O = 0$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$		20	$\mu\text{A}$		
			$V_{CCA} = 5\ \text{V}$ , $V_{CCB} = 0\ \text{V}$		20			
			$V_{CCA} = 0\ \text{V}$ , $V_{CCB} = 5\ \text{V}$		-2			
$I_{CCB}$	Supply current B port	$V_I = V_{CCI}$ or GND, $I_O = 0$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$		20	$\mu\text{A}$		
			$V_{CCA} = 5\ \text{V}$ , $V_{CCB} = 0\ \text{V}$		-2			
			$V_{CCA} = 0\ \text{V}$ , $V_{CCB} = 5\ \text{V}$		20			
	Combined supply current	$V_I = V_{CCI}$ or GND, $I_O = 0$	$V_{CCA} = V_{CCB} = 1.65\ \text{V}$ to $4.5\ \text{V}$		30	$\mu\text{A}$		

## 6.5 Electrical Characteristics (continued)

All typical limits apply over  $T_A = 25^\circ\text{C}$ , and all maximum and minimum limits apply over  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$  (unless otherwise noted).<sup>(1) (2)</sup>

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$\Delta I_{CCA}$	Supply-current change DIR	DIR at $V_{CCA} - 0.6\text{ V}$ , B port = open, A port at $V_{CCA}$ or GND	$V_{CCA} = V_{CCB} = 3\text{ to }5.5\text{ V}$			50	$\mu\text{A}$
$C_i$	Input capacitance control inputs	$V_i = V_{CCA}$ or GND	$V_{CCA} = V_{CCB} = 3.3\text{ V}$		4	5	pF
$C_{io}$	Input and output capacitance A or B port	$V_O = V_{CCA/B}$ or GND	$V_{CCA} = V_{CCB} = 3.3\text{ V}$		8.5	10	pF

- (1)  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.
- (2)  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- (3) The bus-hold circuit can sink at least the minimum low sustaining current at the  $V_{IL}$  maximum.  $I_{BHL}$  should be measured after lowering  $V_{IN}$  to GND and then raising it to  $V_{IL}$  maximum.
- (4) The bus-hold circuit can source at least the minimum high sustaining current at  $V_{IH}$  min.  $I_{BHH}$  should be measured after raising  $V_{IN}$  to  $V_{CC}$  and then lowering it to  $V_{IH}$  min.
- (5) An external driver must source at least  $I_{BHLO}$  to switch this node from low to high.
- (6) An external driver must sink at least  $I_{BHHO}$  to switch this node from high to low.

## 6.6 Switching Characteristics: $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$  (unless otherwise noted) (see [7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
$t_{PLH}, t_{PHL}$	A	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.7	21.9	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.3	9.2	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1	7.4	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.4	7.1	
$t_{PLH}, t_{PHL}$	B	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.9	23.8	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.8	23.6	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.7	23.4	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.7	23.4	
$t_{PHZ}, t_{PLZ}$	$\overline{\text{OE}}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.5	29.6	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.5	29.4	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.5	29.3	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1.4	29.2	
$t_{PHZ}, t_{PLZ}$	$\overline{\text{OE}}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	2.4	32.2	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.9	13.1	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.7	12	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1.3	10.3	
$t_{PZH}, t_{PZL}$	$\overline{\text{OE}}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.4	24	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.4	23.8	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.4	23.7	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.4	23.7	
$t_{PZH}, t_{PZL}$	$\overline{\text{OE}}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.8	32	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.5	16	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.2	12.6	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.9	10.8	

## 6.7 Switching Characteristics: $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$  (unless otherwise noted) (see [Figure 7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
$t_{PLH}, t_{PHL}$	A	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.5	21.4	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.2	9	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.8	6.2	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.6	4.8	
$t_{PLH}, t_{PHL}$	B	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.2	9.3	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1	9.1	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1	8.9	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.9	8.8	
$t_{PHZ}, t_{PLZ}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.4	9	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.4	9	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.4	9	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1.4	9	
$t_{PHZ}, t_{PLZ}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	2.3	29.6	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.8	11	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.7	9.3	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.9	6.9	
$t_{PZH}, t_{PZL}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1	10.9	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1	10.9	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1	10.9	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1	10.9	
$t_{PZH}, t_{PZL}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.7	28.2	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.5	12.9	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.2	9.4	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1	6.9	



## 6.8 Switching Characteristics: $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$  (unless otherwise noted) (see [Figure 7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
$t_{PLH}, t_{PHL}$	A	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.5	21.2	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.1	8.8	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.8	6.2	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.5	4.4	
$t_{PLH}, t_{PHL}$	B	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.8	7.2	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.8	6.2	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.7	6.1	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.6	6	
$t_{PHZ}, t_{PLZ}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.6	8.2	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.6	8.2	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.6	8.2	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	1.6	8.2	
$t_{PHZ}, t_{PLZ}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	2.1	29	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.7	10.3	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.5	8.6	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.8	6.3	
$t_{PZH}, t_{PZL}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.8	8.1	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.8	8.1	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.8	8.1	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.8	8.1	
$t_{PZH}, t_{PZL}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.8	27.7	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.4	12.4	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.1	8.5	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.9	6.4	

## 6.9 Switching Characteristics: $V_{CCA} = 5\text{ V} \pm 0.5\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 5\text{ V} \pm 0.5\text{ V}$  (unless otherwise noted) (see [Figure 7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
$t_{PLH}$ , $t_{PHL}$	A	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.5	21.4	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1	8.8	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.7	6	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.4	4.2	
$t_{PLH}$ , $t_{PHL}$	B	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.7	7	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.4	4.8	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.3	4.5	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.3	4.3	
$t_{PHZ}$ , $t_{PLZ}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.3	5.4	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.3	5.4	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.3	5.4	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.3	5.4	
$t_{PHZ}$ , $t_{PLZ}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	2	28.7	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.6	9.7	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1.4	8	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.7	5.7	
$t_{PZH}$ , $t_{PZL}$	$\overline{OE}$	A	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	0.7	6.4	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	0.7	6.4	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	0.7	6.4	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.7	6.4	
$t_{PZH}$ , $t_{PZL}$	$\overline{OE}$	B	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$	1.5	27.6	ns
			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$	1.3	11.4	
			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$	1	8.1	
			$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$	0.9	6.5	

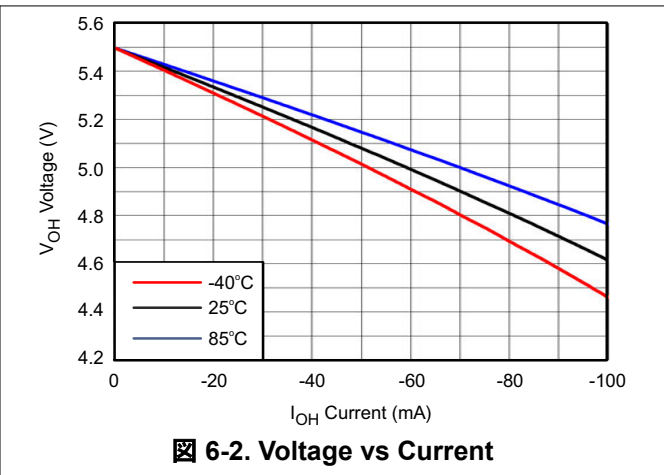
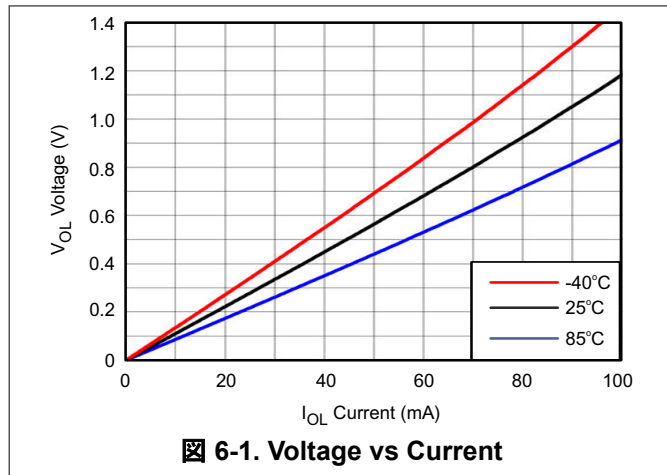
### 6.10 Operating Characteristics

T<sub>A</sub> = 25°C

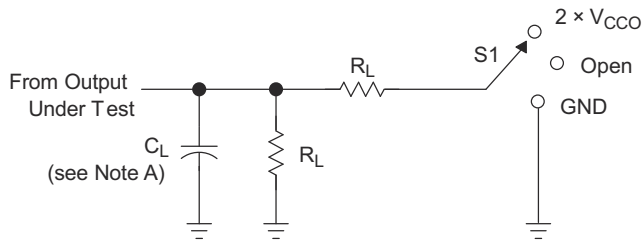
PARAMETER <sup>(1)</sup>		TEST CONDITIONS		TYP	UNIT
C <sub>pdA</sub> <sup>(2)</sup>	A-port input, B-port output	C <sub>L</sub> = 0, f = 10 MHz, t <sub>r</sub> = t <sub>f</sub> = 1 ns	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	2	pF
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5 V	2	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V	2	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 5 V	3	
	B-port input, A-port output	C <sub>L</sub> = 0, f = 10 MHz, t <sub>r</sub> = t <sub>f</sub> = 1 ns	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	12	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5 V	13	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V	13	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 5 V	16	
C <sub>pdB</sub> <sup>(2)</sup>	A-port input, B-port output	C <sub>L</sub> = 0, f = 10 MHz, t <sub>r</sub> = t <sub>f</sub> = 1 ns	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	13	pF
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5 V	13	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V	14	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 5 V	16	
	B-port input, A-port output	C <sub>L</sub> = 0, f = 10 MHz, t <sub>r</sub> = t <sub>f</sub> = 1 ns	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	2	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5 V	2	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V	2	
			V <sub>CCA</sub> = V <sub>CCB</sub> = 5 V	3	

- (1) See *CMOS Power Consumption and Cpd Calculation*, SCAA035.
- (2) Power dissipation capacitance per transceiver.

### 6.11 Typical Characteristics



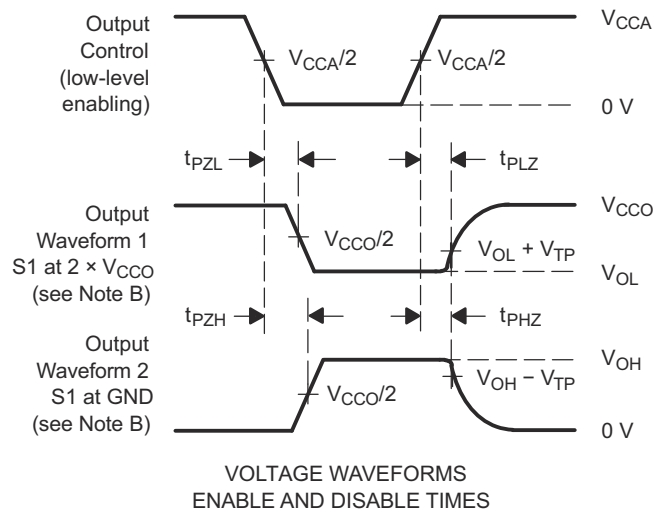
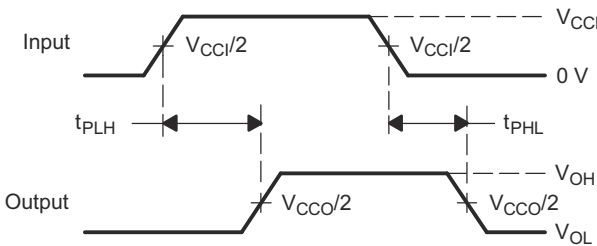
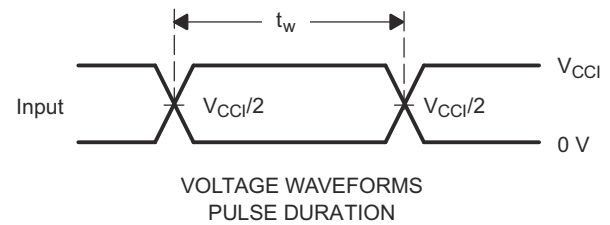
## 7 Parameter Measurement Information



LOAD CIRCUIT

TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	$2 \times V_{CCO}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CCO}$	$C_L$	$R_L$	$V_{TP}$
$1.8\text{ V} \pm 0.15\text{ V}$	15 pF	2 kW	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	15 pF	2 kW	0.15 V
$3.3\text{ V} \pm 0.3\text{ V}$	15 pF	2 kW	0.3 V
$5\text{ V} \pm 0.5\text{ V}$	15 pF	2 kW	0.3 V



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR = 10 MHz,  $Z_O = 50\ \Omega$ ,  $dv/dt \geq 1\text{ V/ns}$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{jis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
  - I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.
  - J. All parameters and waveforms are not applicable to all devices.

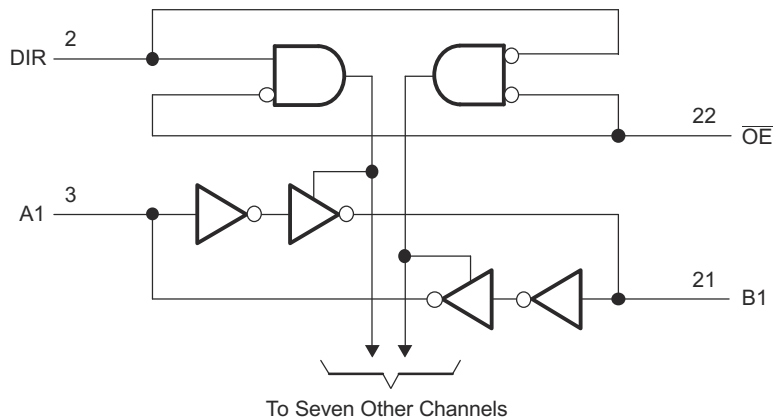
### 7-1. Load Circuit and Voltage Waveforms

## 8 Detailed Description

### 8.1 Overview

The SN74LVCH8T245 is an 8-bit, dual supply noninverting voltage level translator. Pins A1 through A4, and the control pins (DIR and  $\overline{OE}$ ) are referenced to  $V_{CCA}$ , while pins B1 through B4 are referenced to  $V_{CCB}$ . Both the A port and B port can accept I/O voltages ranging from 1.65 V to 5.5 V. The high on DIR allows data transmission from Port A to Port B, and a low on DIR allows data transmission from Port B to Port A. For more information, see [AVC Logic Family Technology and Applications](#).

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Fully Configurable Dual-Rail Design

Both  $V_{CCA}$  and  $V_{CCB}$  can be supplied at any voltage from 1.65 V to 5.5 V, making the device suitable for translating between any of the voltage nodes: 1.8 V, 2.5 V, 3.3 V, and 5 V.

#### 8.3.2 Partial-Power-Down Mode Operation

$I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. This can occur in applications where subsections of a system are powered down (partial power down) to reduce power consumption. The maximum leakage into or out of any input or output pin on the device is specified by  $I_{off}$  in the [Electrical Characteristics](#).

#### 8.3.3 Active Bus Hold Circuitry

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state, which helps with board space savings and reduced component costs. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended as this eliminates the bus-hold feature.

#### 8.3.4 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. Two outputs can be connected together for 2X stronger output drive strength. The electrical and thermal limits defined in the [Absolute Maximum Ratings](#) must be followed at all times.

#### 8.3.5 $V_{CC}$ Isolation

The  $V_{CC}$  isolation feature ensures that if either  $V_{CCA}$  or  $V_{CCB}$  are at GND (or  $< 0.4$  V), both ports will be in a high-impedance state ( $I_{OZ}$  shown in [Electrical Characteristics](#)). This prevents false logic levels from being presented to either bus.

## 8.4 Device Functional Modes

表 8-1 lists the functional modes of the SN74LVCH8T245.

**表 8-1. Function Table (Each 8-Bit Section)**

CONTROL INPUTS <sup>(1)</sup>		OUTPUT CIRCUITS		OPERATION
$\overline{OE}$	DIR	A PORT	B PORT	
L	L	Enabled	Hi-Z	B data to A bus
L	H	Hi-Z	Enabled	A data to B bus
H	X	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os are always active.

## 9 Application and Implementation

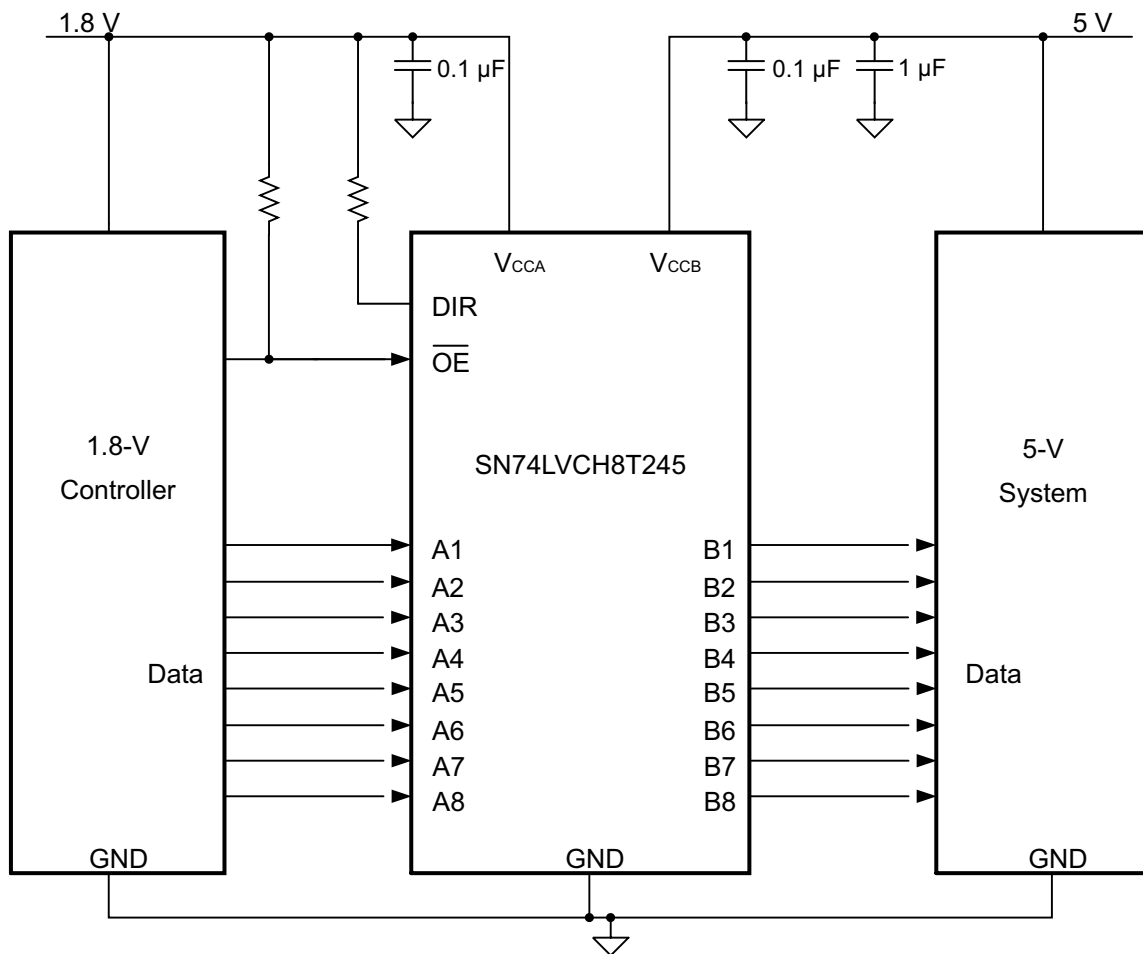
### 注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 9.1 Application Information

The SN74LVCH8T245 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The maximum output current can be up to 32 mA when device is powered by 5 V.

### 9.2 Typical Application



☒ 9-1. Typical Application Circuit

### 9.2.1 Design Requirements

For this design example, use the parameters listed in 表 9-1.

表 9-1. Design Parameters

PARAMETERS	VALUES
Input voltage	1.65 V to 5.5 V
Output voltage	1.65 V to 5.5 V

### 9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74LVCH8T245 to determine the input voltage range. For a valid logic high, the value must exceed the  $V_{IH}$  of the input port. For a valid logic low, the value must be less than the  $V_{IL}$  of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74LVCH8T245 is driving to determine the output voltage range.

#### 9.2.2.1 Enable Times

Calculate the enable times for the SN74LVCH8T245 using 式 1, 式 2, 式 3, and 式 4:

$$t_{PZH} (\text{DIR to A}) = t_{PLZ} (\text{DIR to B}) + t_{PLH} (\text{B to A}) \quad (1)$$

$$t_{PZL} (\text{DIR to A}) = t_{PHZ} (\text{DIR to B}) + t_{PHL} (\text{B to A}) \quad (2)$$

$$t_{PZH} (\text{DIR to B}) = t_{PLZ} (\text{DIR to A}) + t_{PLH} (\text{A to B}) \quad (3)$$

$$t_{PZL} (\text{DIR to B}) = t_{PHZ} (\text{DIR to A}) + t_{PHL} (\text{A to B}) \quad (4)$$

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the device initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

### 9.2.3 Application Curve

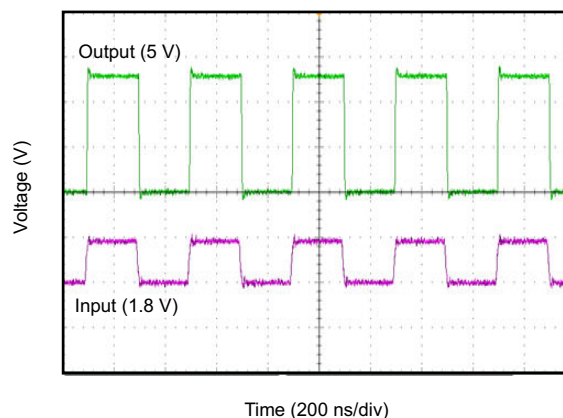


图 9-2. Translation Up (1.8 V to 5 V) at 2.5 MHz



## 10 Power Supply Recommendations

The output-enable ( $\overline{OE}$ ) input circuit is designed so that it is supplied by  $V_{CCA}$  and when the  $\overline{OE}$  input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the  $\overline{OE}$  input pin must be tied to  $V_{CCA}$  through a pullup resistor and must not be enabled until  $V_{CCA}$  and  $V_{CCB}$  are fully ramped and stable. The minimum value of the pullup resistor to  $V_{CCA}$  is determined by the current-sinking capability of the driver.

$V_{CCA}$  or  $V_{CCB}$  can be powered up first. If the SN74LVCH8T245 is powered up in a permanently enabled state (for example  $\overline{OE}$  is always kept low), pullup resistors are recommended at the input. This ensures proper, glitch-free, power-up. For more information, see [Designing with SN4LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters](#). In addition, the  $\overline{OE}$  pin may be shorted to GND if the application does not require use of the high-impedance state at any time.

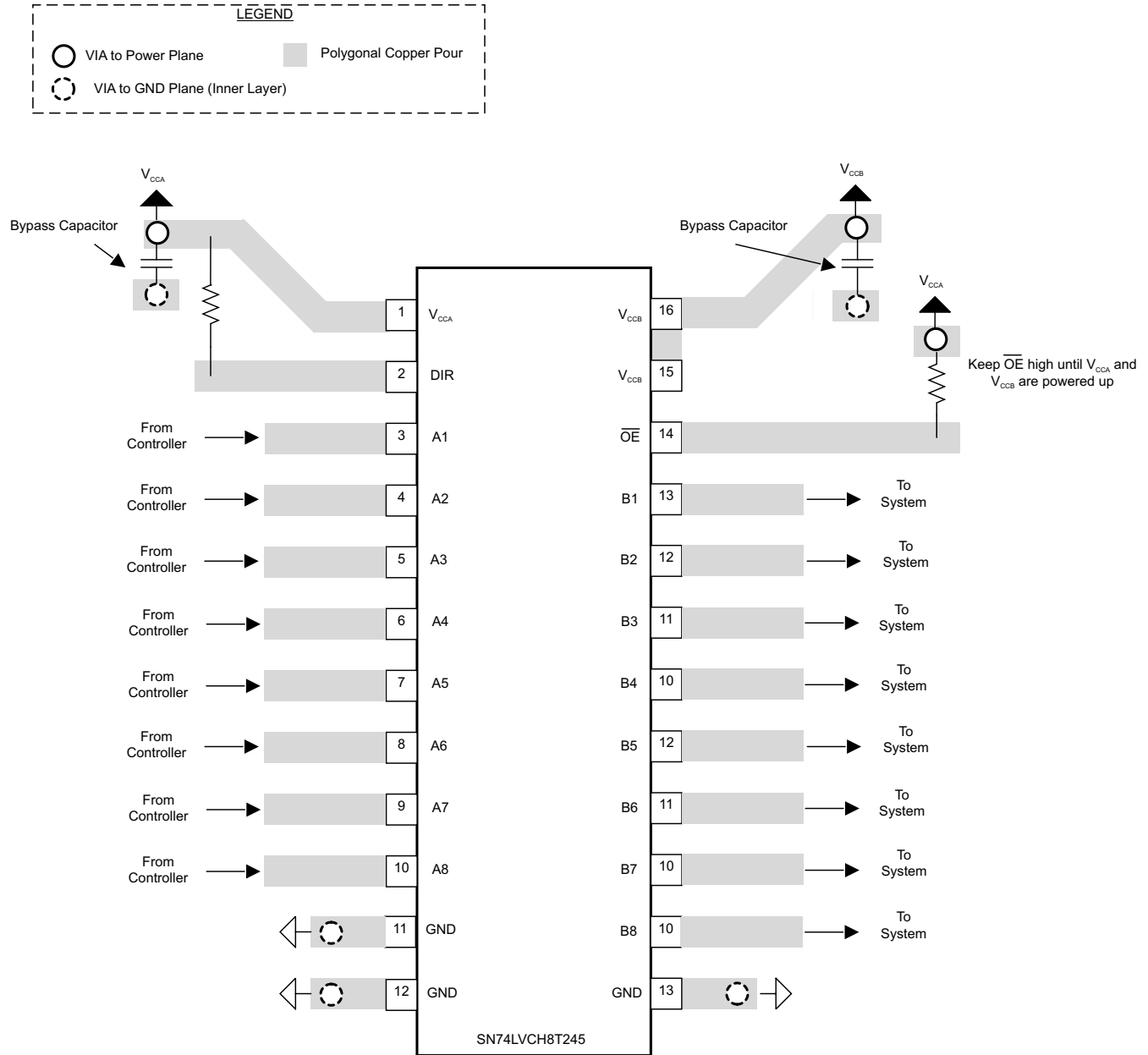
## 11 Layout

### 11.1 Layout Guidelines

To ensure reliability of the device, TI recommends the following common printed-circuit board layout guidelines.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors helps adjust rise and fall times of signals depending on the system requirements.

### 11.2 Layout Example



**11-1. SN74LVCH8T245 Layout**

## 12 Device and Documentation Support

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Designing with SN74LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters](#)
- Texas Instruments, [Bus-Hold Circuit](#)
- Texas Instruments, [AVC Logic Family Technology and Applications](#)
- Texas Instruments, [CMOS Power Consumption and Cpd Calculation](#)

### 12.2 ドキュメントの更新通知を受け取る方法

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### 12.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVCH8T245DBR	ACTIVE	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	<a href="#">Samples</a>
SN74LVCH8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	<a href="#">Samples</a>
SN74LVCH8T245PW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	<a href="#">Samples</a>
SN74LVCH8T245PWE4	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	<a href="#">Samples</a>
SN74LVCH8T245PWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	<a href="#">Samples</a>
SN74LVCH8T245RHLR	ACTIVE	VQFN	RHL	24	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NJ245	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCH8T245DBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVCH8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVCH8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVCH8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVCH8T245RHLLR	VQFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCH8T245DBR	SSOP	DB	24	2000	356.0	356.0	35.0
SN74LVCH8T245DGVR	TVSOP	DGV	24	2000	356.0	356.0	35.0
SN74LVCH8T245PWR	TSSOP	PW	24	2000	356.0	356.0	35.0
SN74LVCH8T245PWR	TSSOP	PW	24	2000	356.0	356.0	35.0
SN74LVCH8T245RHLR	VQFN	RHL	24	1000	210.0	185.0	35.0

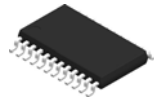
**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74LVCH8T245PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74LVCH8T245PWE4	PW	TSSOP	24	60	530	10.2	3600	3.5



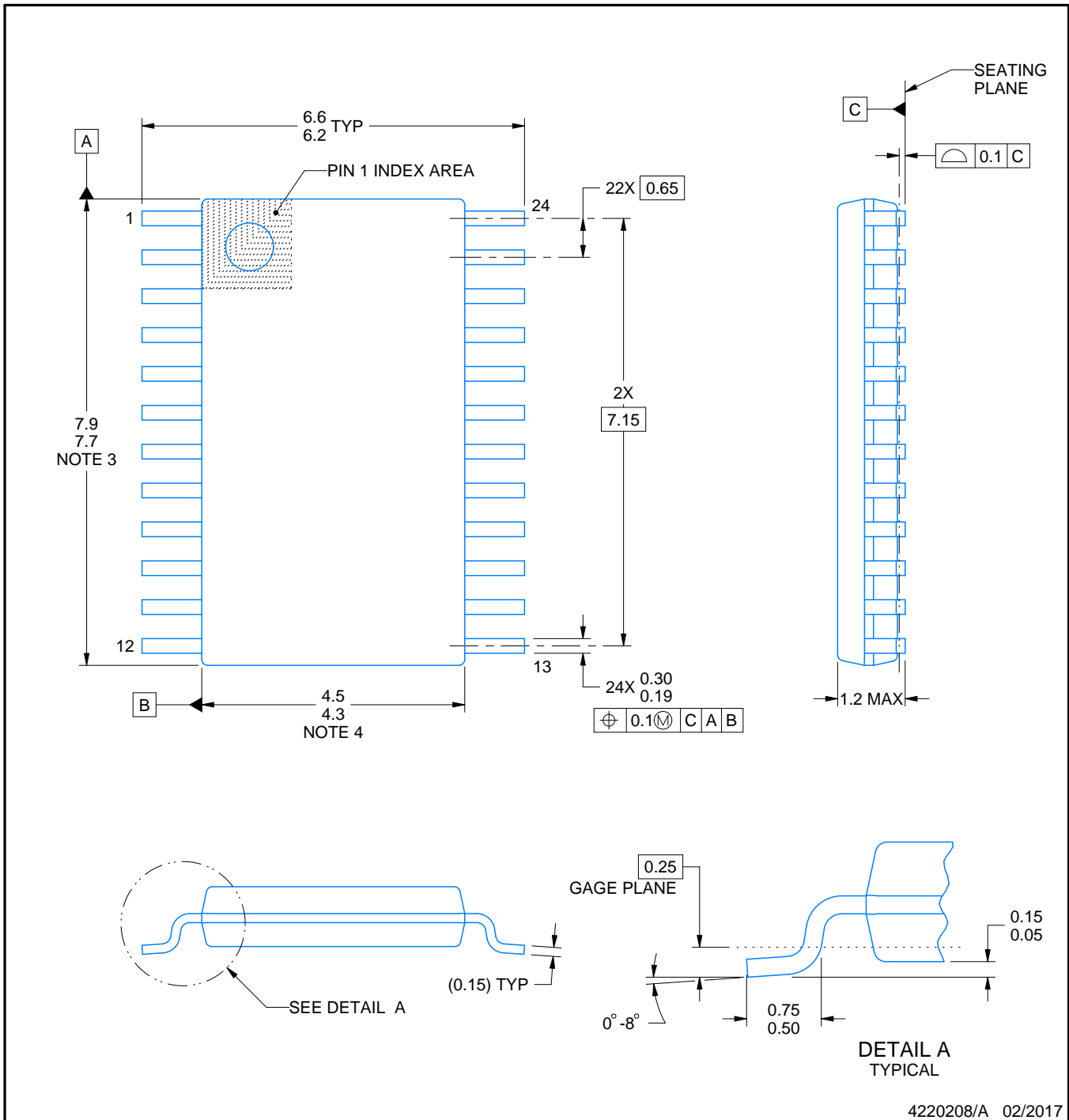
# PW0024A



## PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220208/A 02/2017

### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220208/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

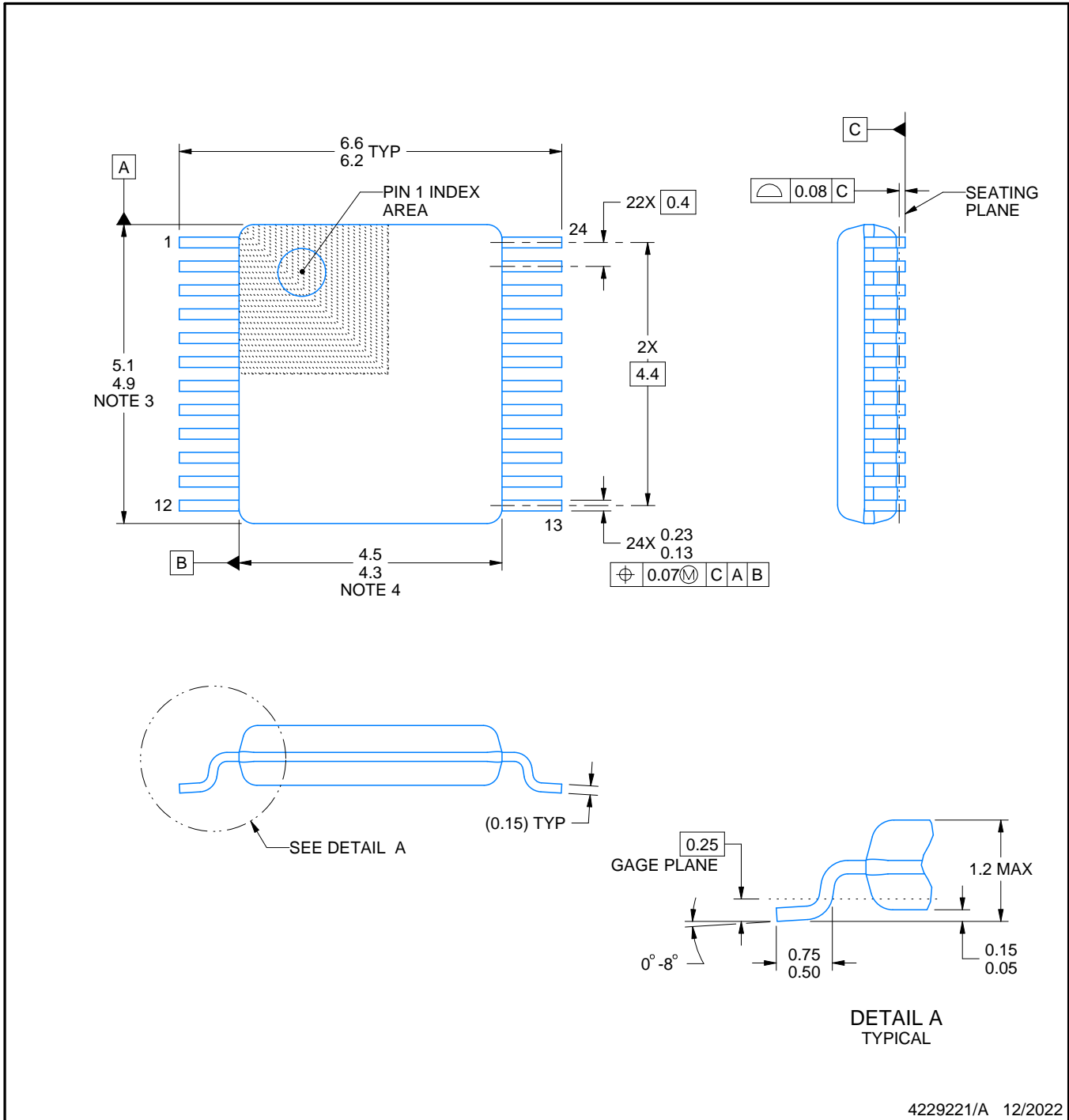
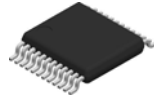
DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150



4229221/A 12/2022

NOTES:

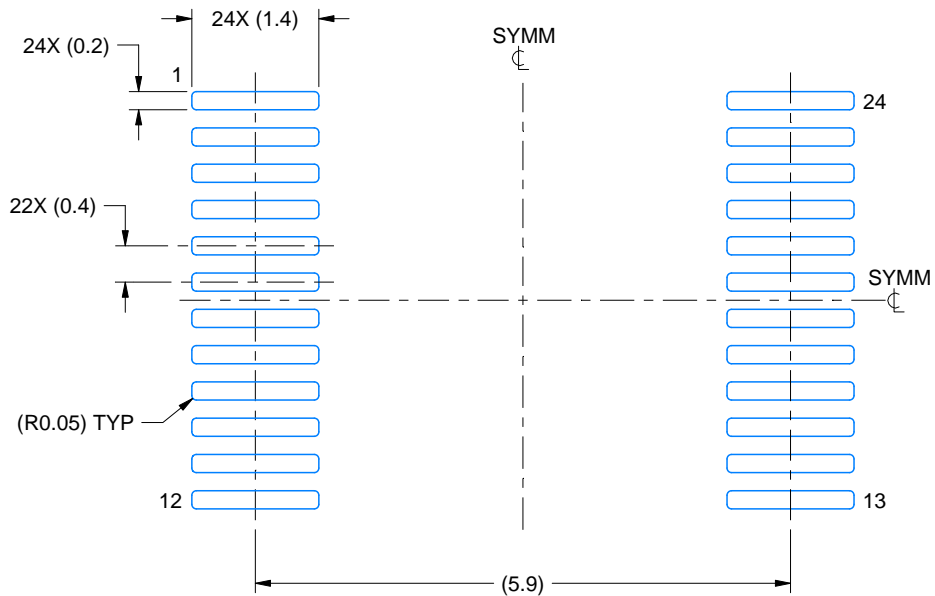
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

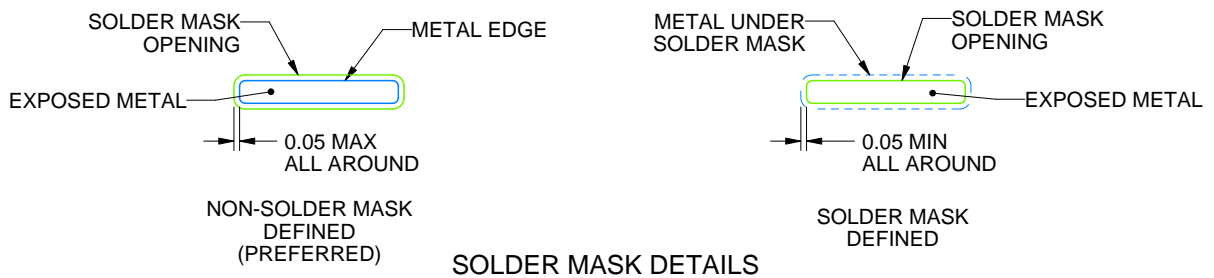
DGV0024A

TVSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 12X



SOLDER MASK DETAILS

4229221/A 12/2022

NOTES: (continued)

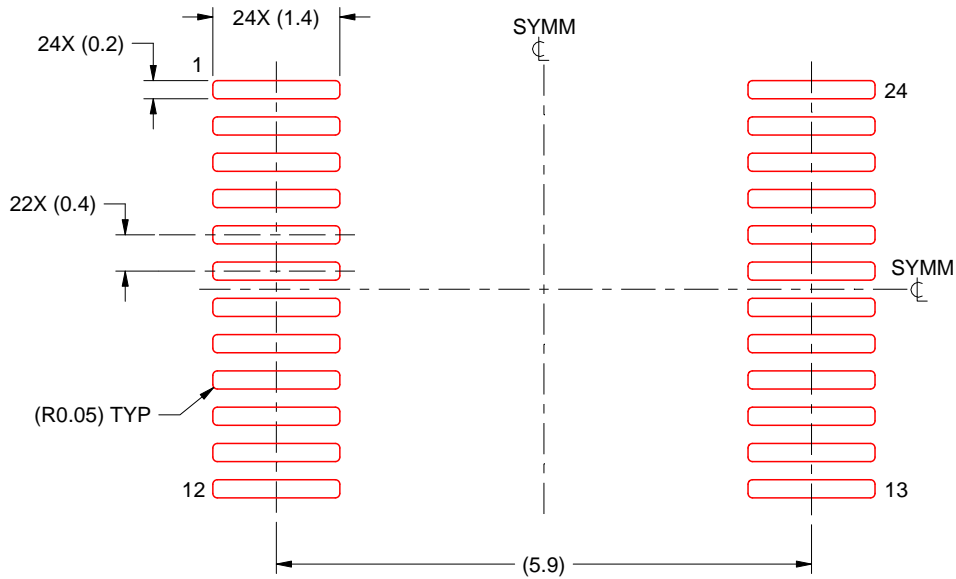
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DGV0024A

TVSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

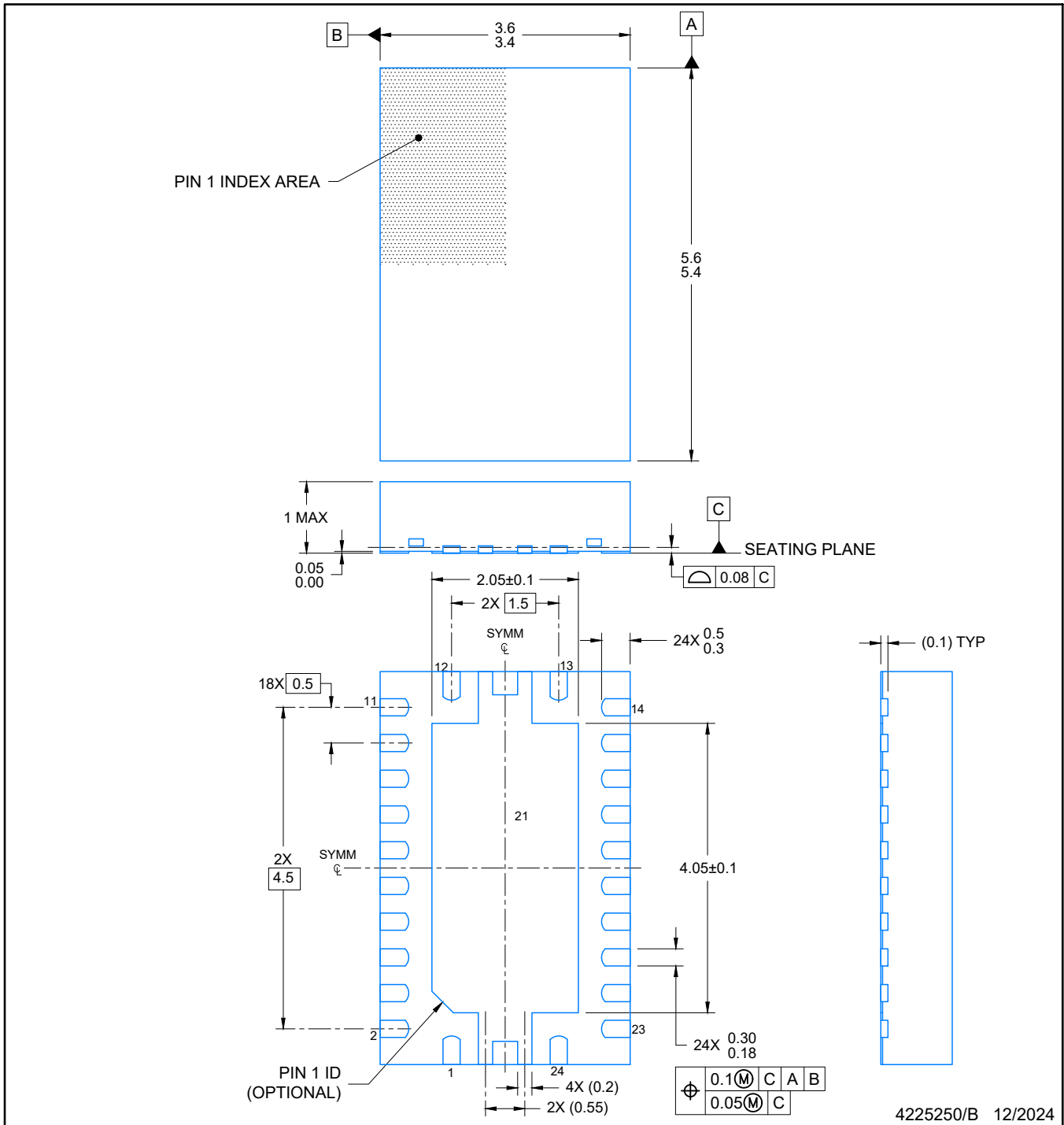


SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 12X

4229221/A 12/2022

NOTES: (continued)

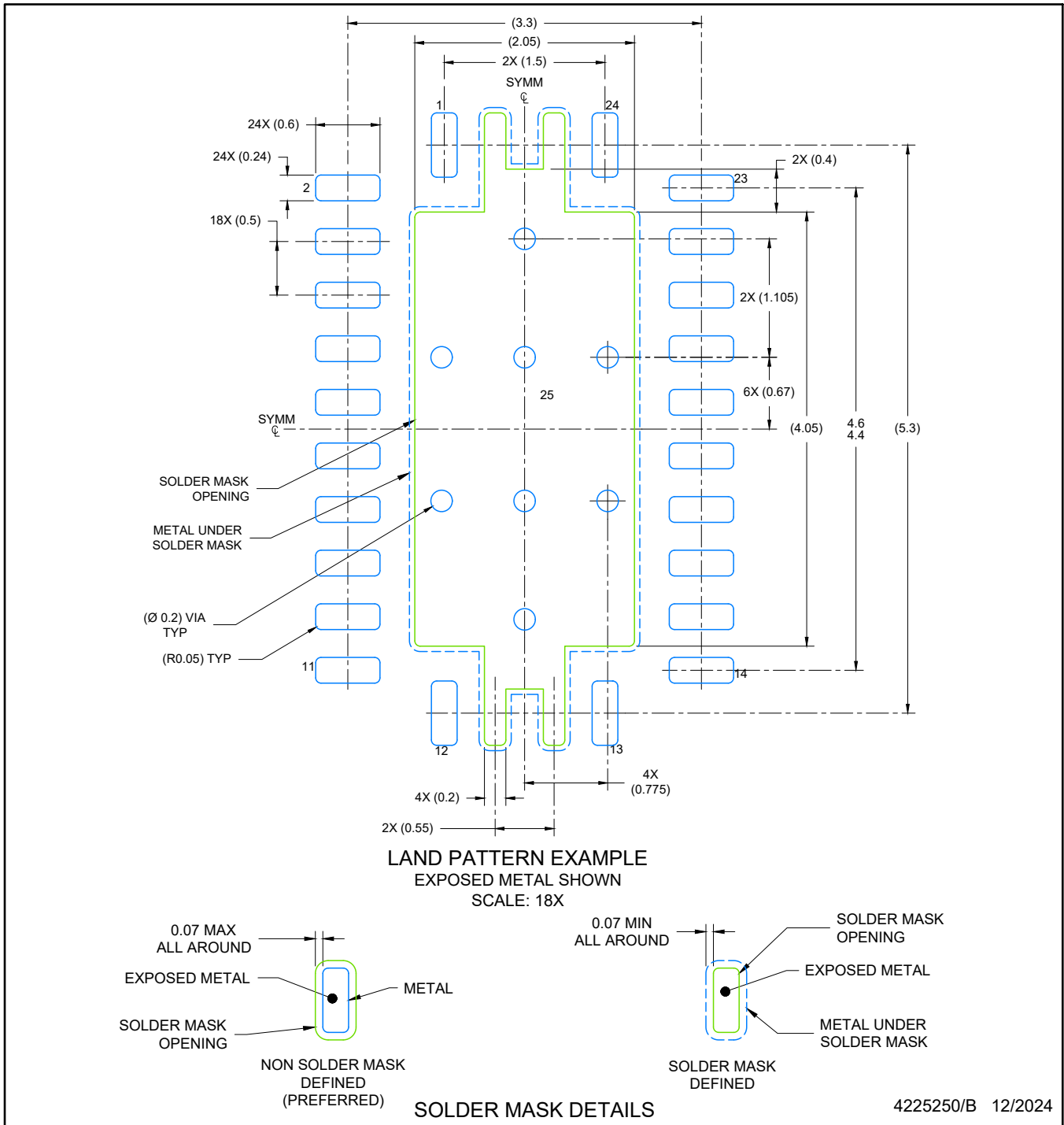
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.





NOTES: (continued)

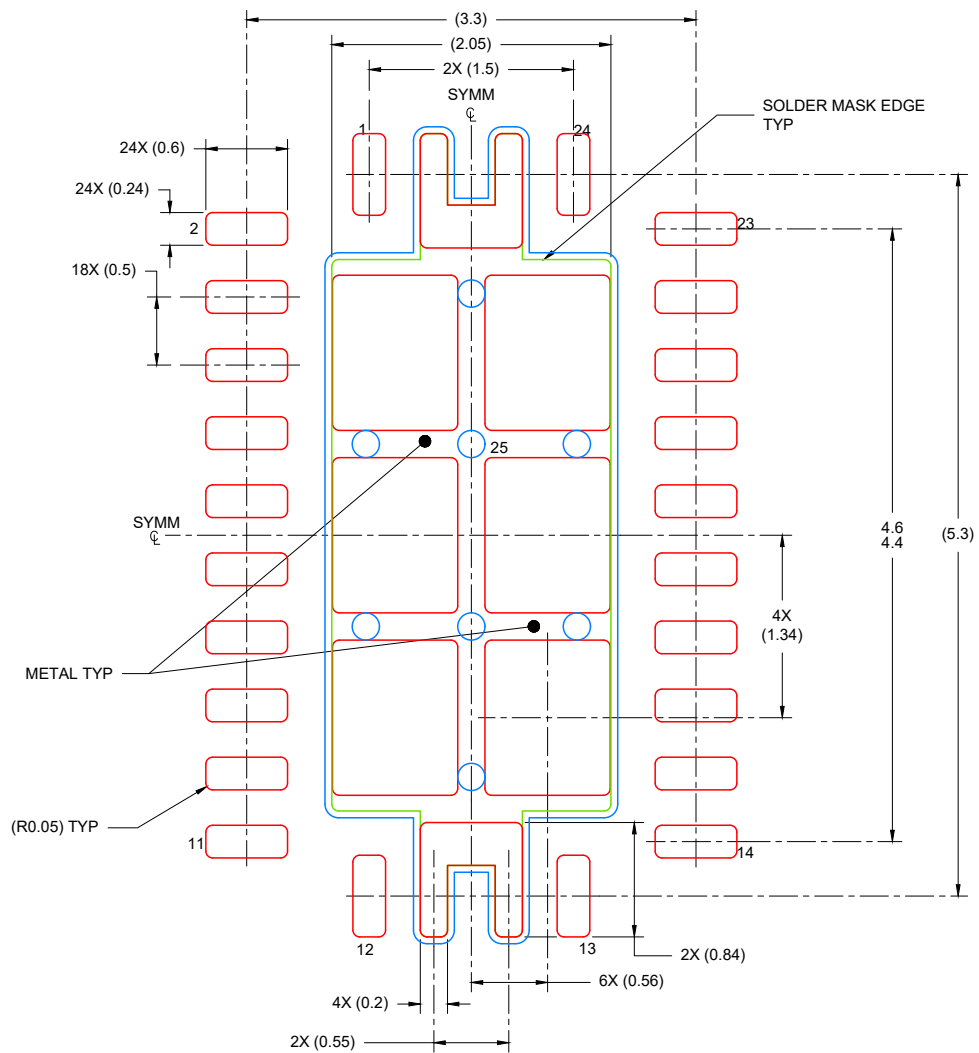
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

RHL0024A

PLASTIC QUAD FLATPACK- NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
80% PRINTED COVERAGE BY AREA  
SCALE: 18X

4225250/B 12/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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